

T-03-19

MOTOROLA
SEMICONDUCTOR
TECHNICAL DATA
Designers Data Sheet
STUD MOUNTED
FAST RECOVERY POWER RECTIFIERS

... designed for special applications such as dc power supplies, inverters, converters, ultrasonic systems, choppers, low RF interference, sonar power supplies and free wheeling diodes. A complete line of fast recovery rectifiers having typical recovery time of 150 nanoseconds providing high efficiency at frequencies to 250 kHz.

Designer's Data for "Worst Case" Conditions

The Designers Data sheets permit the design of most circuits entirely from the information presented. Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

MAXIMUM RATINGS

Rating	Symbol	MR860	MR861	MR862	MR864	MR866	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	50	100	200	400	600	Volts
Working Peak Reverse Voltage	V_{RWM}						
DC Blocking Voltage	V_R	75	150	250	450	650	Volts
Non-Repetitive Peak Reverse Voltage	V_{RSM}	35	70	140	280	420	Volts
RMS Reverse Voltage	$V_R(RMS)$						
Average Rectified Forward Current (Single phase, resistive load, $T_C = 100^\circ C$)	I_O	40					Amps
Non-Repetitive Peak Surge Current (surge applied at rated load conditions)	I_{FSM}	350					Amps
Operating Junction Temperature Range	T_J	-65 to +160					$^\circ C$
Storage Temperature Range	T_{stg}	-65 to +175					$^\circ C$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.85	$^\circ C/W$

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Typ	Max	Unit
Instantaneous Forward Voltage ($I_F = 125$ Amp, $T_J = 150^\circ C$)	V_F	—	1.3	1.6	Volts
Forward Voltage ($I_F = 40$ Amp, $T_C = 25^\circ C$)	V_F	—	1.0	1.4	Volts
Reverse Current (rated dc voltage) $T_C = 25^\circ C$ $T_C = 100^\circ C$	I_R	—	25	50	μA mA

REVERSE RECOVERY CHARACTERISTICS

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Recovery Time ($I_F = 1.0$ Amp to $V_R = 30$ Vdc, Figure 16) ($I_{FSM} = 35$ Amp, $di/dt = 25$ A/ μs , Figure 17)	t_{rr}	—	150 200	200 400	ns
Reverse Recovery Current ($I_F = 1.0$ Amp to $V_R = 30$ Vdc, Figure 16)	$I_{RM}(REC)$	—	2.0	3.0	Amp

MECHANICAL CHARACTERISTICS

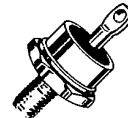
CASE: Welded, hermetically sealed

FINISH: All external surfaces corrosion resistant and readily solderable

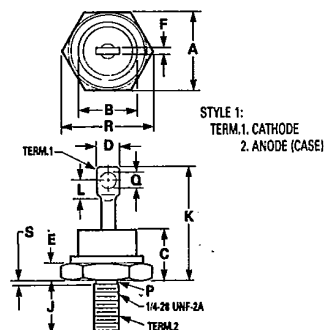
POLARITY: Cathode to Case

WEIGHT: 17 Grams (Approximately)

STUD TORQUE: 25 in. lbs.

MR860 MR861
MR862 MR864
MR866
FAST RECOVERY
POWER RECTIFIERS
50-600 VOLTS
40 AMPERES


3


NOTES:

- DIM "P" IS DIA.
- CHAMFER OR UNDERCUT ON ONE OR BOTH ENDS OF HEXAGONAL BASE IS OPTIONAL.
- ANGULAR ORIENTATION AND CONTOUR OF TERMINAL ONE IS OPTIONAL.
- THREADS ARE PLATED.
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5, 1973.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	16.94	17.45	0.669	0.687
B	—	16.94	—	0.667
C	—	11.43	—	0.450
D	—	9.53	—	0.375
E	7.92	5.08	0.115	0.200
F	—	2.03	—	0.080
J	10.72	11.51	0.422	0.453
K	—	25.40	—	1.000
L	3.86	—	0.156	—
P	5.59	6.32	0.220	0.249
Q	3.56	4.45	0.140	0.175
R	—	20.16	—	0.794
S	—	2.26	—	0.089

CASE 257-01
DO-203AB
METAL

MR860, MR861, MR862, MR864, MR866

T-03-19

FIGURE 1 — FORWARD VOLTAGE

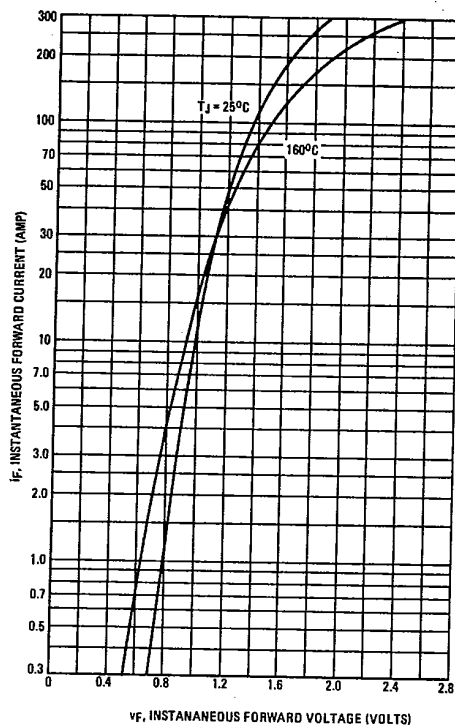
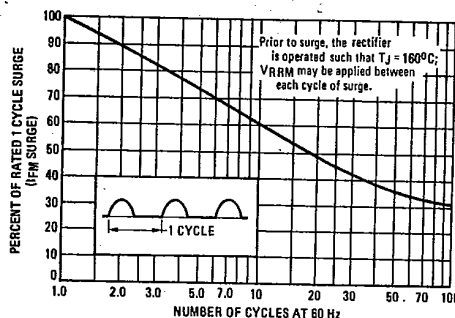
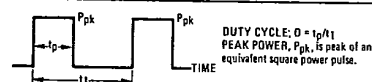


FIGURE 2 — MAXIMUM SURGE CAPABILITY



NOTE 1



To determine maximum junction temperature of the diode in a given situation, the following procedure is recommended:

The temperature of the case should be measured using a thermocouple placed on the case at the temperature reference point (see Note 3). The thermal mass connected to the case is normally large enough so that it will not significantly respond to heat surges generated in the diode as a result of pulsed operation once steady-state conditions are achieved. Using the measured value of T_C , the junction temperature may be determined by:

$$T_J = T_C + \Delta T_{JC}$$

where ΔT_{JC} is the increase in junction temperature above the case temperature. It may be determined by:

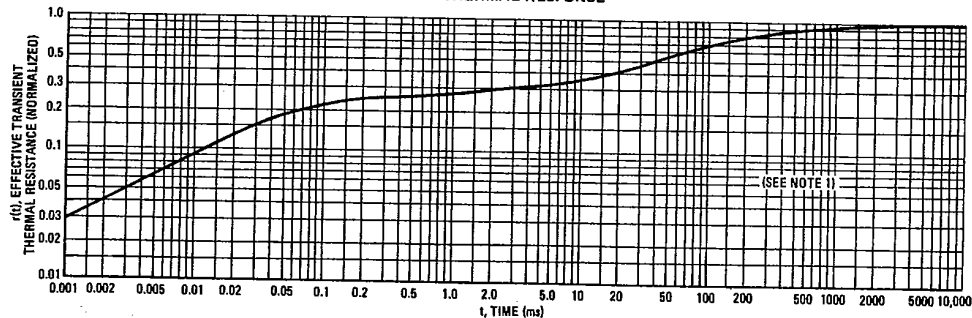
$$\Delta T_{JC} = P_{pk} \cdot R_{\theta JC} [D + (1-D) \cdot r(t_1 + t_p) + r(t_p) - r(t_1)]$$

where

$r(t)$ = normalized value of transient thermal resistance at time, t , from Figure 3, i.e.:

$r(t_1 + t_p)$ = normalized value of transient thermal resistance at time $t_1 + t_p$.

FIGURE 3 — THERMAL RESPONSE

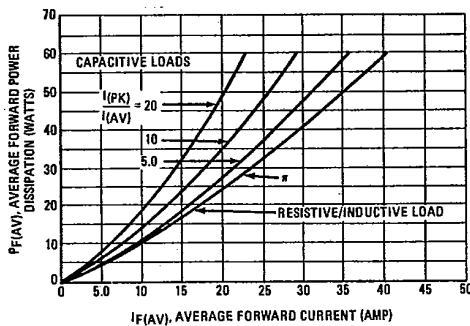


MR860, MR861, MR862, MR864, MR866

T-03-19

SINE WAVE INPUT

FIGURE 4 - FORWARD POWER DISSIPATION



SQUARE WAVE INPUT

FIGURE 5 - FORWARD POWER DISSIPATION

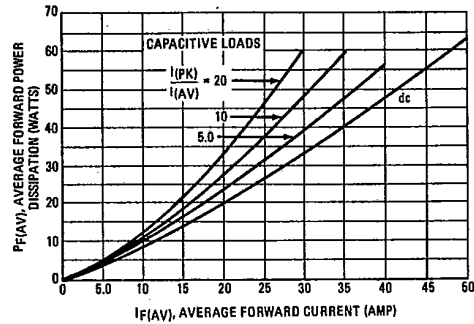


FIGURE 6 - CURRENT DERATING

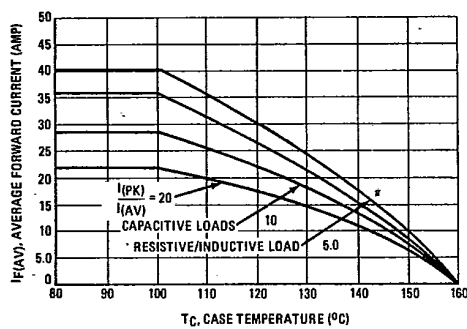


FIGURE 7 - CURRENT DERATING

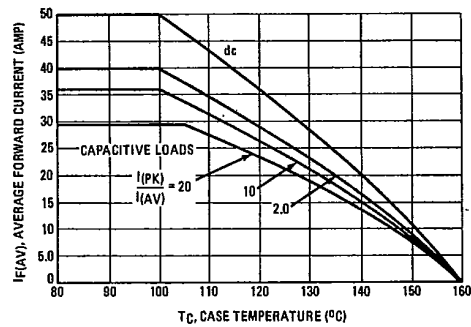


FIGURE 8 - TYPICAL REVERSE CURRENT

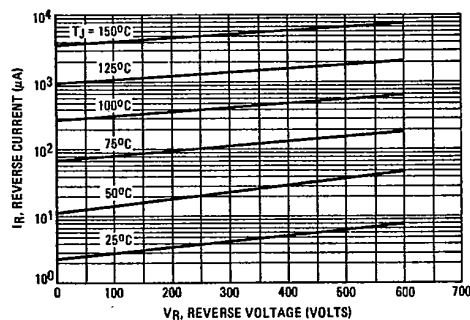
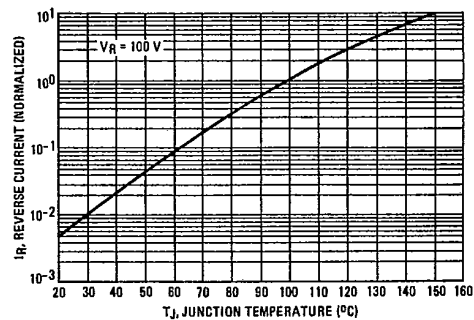


FIGURE 9 - NORMALIZED REVERSE CURRENT



MR860, MR861, MR862, MR864, MR866

T-03-19

FIGURE 10 — FORWARD RECOVERY TIME

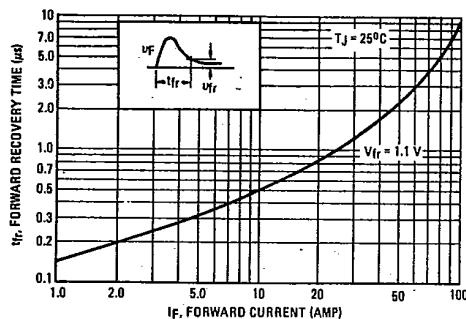
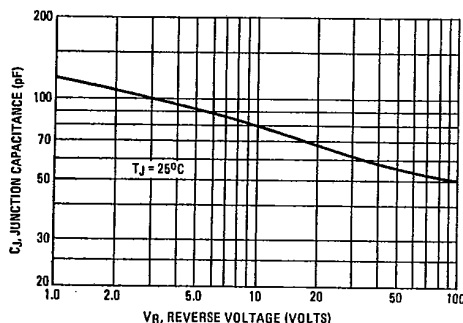


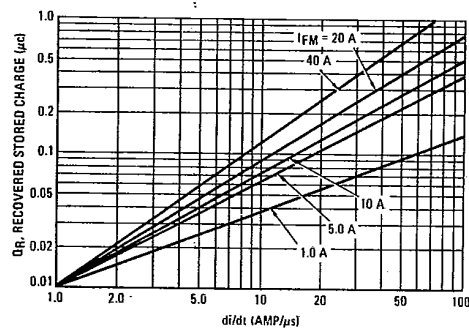
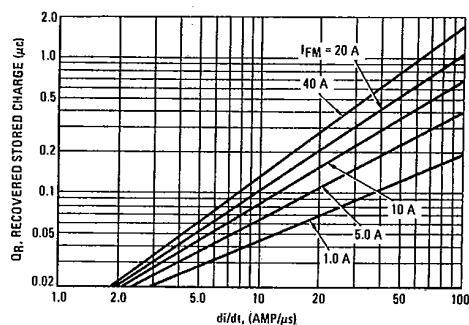
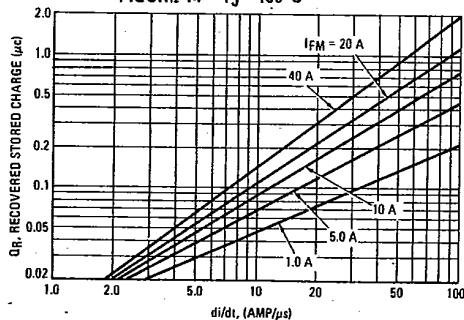
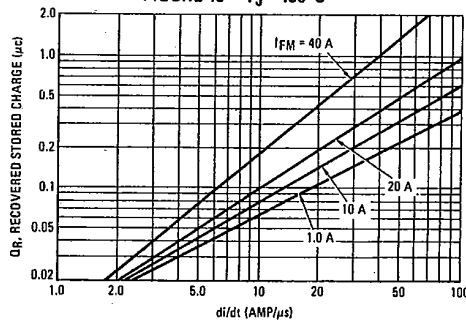
FIGURE 11 — JUNCTION CAPACITANCE



TYPICAL RECOVERED STORED CHARGE DATA

FIGURE 12 — $T_J = 25^\circ C$

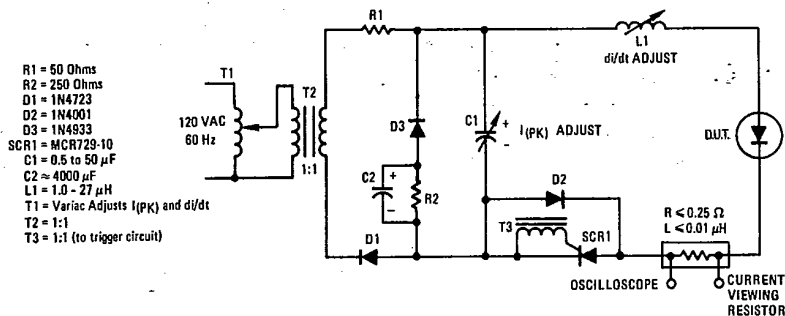
(See Note 2)

FIGURE 13 — $T_J = 75^\circ C$ FIGURE 14 — $T_J = 100^\circ C$ FIGURE 15 — $T_J = 150^\circ C$ 

MR860, MR861, MR862, MR864, MR866

T-03-19

FIGURE 16 — JEDEC REVERSE RECOVERY CIRCUIT



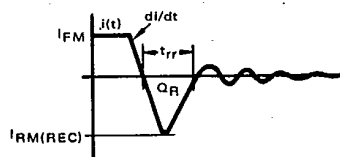
NOTE 2

Reverse recovery time is the period which elapses from the time that the current, thru a previously forward biased rectifier diode, passes thru zero going negatively until the reverse current recovers to a point which is less than 10% peak reverse current.

Reverse recovery time is a direct function of the forward current prior to the application of reverse voltage.

For any given rectifier, recovery time is very circuit dependent. Typical and maximum recovery time of all Motorola fast recovery power rectifiers are rated under a fixed set of conditions using $I_F = 1.0 \text{ A}$, $V_R = 30 \text{ V}$. In order to cover all circuit conditions, curves are given for typical recovered stored charge versus commutation di/dt for various levels of forward current and for junction temperatures of 25°C , 75°C , 100°C , and 150°C .

To use these curves, it is necessary to know the forward current level just before commutation, the circuit commutation di/dt , and the operating junction temperature. The reverse recovery test current waveform for all Motorola fast recovery rectifiers is shown.



From stored charge curves versus di/dt , recovery time (t_{rr}) and peak reverse recovery current ($I_{RM(REC)}$) can be closely approximated using the following formulas:

$$t_{rr} = 1.41 \times \left[\frac{Q_R}{di/dt} \right]^{1/2}$$

$$I_{RM(REC)} = 1.41 \times [Q_R \times di/dt]^{1/2}$$